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## P-Channel Enhancement-Mode Lateral MOSFET

### Features

- ▶ Ultra-low threshold
- ▶ High input impedance
- ▶ Low input capacitance
- ▶ Fast switching speeds
- ▶ Low on-resistance
- ▶ Freedom from secondary breakdown
- ▶ Low input and output leakage

### Applications

- ▶ Logic level interfaces
- ▶ Solid state relays
- ▶ Battery operated systems
- ▶ Photo voltaic drives
- ▶ Analog switches
- ▶ General purpose line drivers

### Ordering Information

Part Number	Package Options	Packing
LP0701LG-G	8-Lead SOIC	2500/Reel
LP0701N3-G	TO-92	1000/Bag
LP0701N3-G P002	TO-92	2000/Reel
LP0701N3-G P003	TO-92	2000/Reel
LP0701N3-G P005	TO-92	2000/Reel
LP0701N3-G P013	TO-92	2000/Reel
LP0701N3-G P014	TO-92	2000/Reel

-G denotes a lead (Pb)-free / RoHS compliant package

Refer to 'P0xx' Tape & Reel Specs for P002, P003, P005, P013, and P014  
TO-92 Taping Specifications and Winding Styles

### Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	$BV_{DSS}$
Drain-to-gate voltage	$BV_{DGS}$
Gate-to-source voltage	$\pm 10V$
Operating and storage temperature	-55°C to +150°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

### General Description

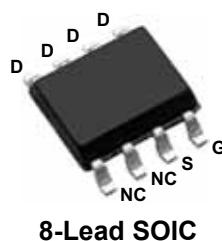
These enhancement-mode (normally-off) transistors utilize a lateral MOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces devices with the power handling capabilities of bipolar transistors and with the high input impedance and negative temperature coefficient inherent in MOS devices.

Characteristic of all MOS structures, these devices are free from thermal runaway and thermally induced secondary breakdown. The low threshold voltage and low on-resistance characteristics are ideally suited for hand held, battery operated applications.

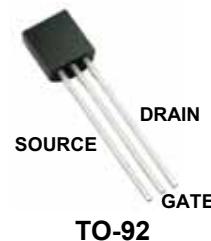
### Product Summary

$BV_{DSS}/BV_{DGS}$	$R_{DS(ON)}$	$V_{GS(TH)}$	$I_{D(ON)}$
-16.5V	3.0k $\Omega$	-1.0V (max)	3.0mA (min)

### Pin Configuration



8-Lead SOIC



TO-92

### Product Marking



YY = Year Sealed  
WW = Week Sealed  
L = Lot Number  
\_\_\_\_\_ = "Green" Packaging

Package may or may not include the following marks: Si or 

8-Lead SOIC



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TO-92

## Thermal Characteristics

Package	$I_D$ (continuous) <sup>†</sup> (mA)	$I_D$ (pulsed) <sup>†</sup> (A)	Power Dissipation @ $T_c = 25^\circ\text{C}$ (W)	$\theta_{ja}$ (°C/W)	$I_{DR}$ (mA)	$I_{DRM}$ (A)
8-Lead SOIC	-700	-1.25	1.5 <sup>‡</sup>	101 <sup>‡</sup>	-700	-1.25
TO-92	-500	-1.25	1.0	132	-500	-1.25

### Notes:

<sup>†</sup>  $I_D$  (continuous) is limited by max rated  $T_j$ .  
<sup>‡</sup> Mounted on FR4 board, 25mm x 25mm x 1.57mm

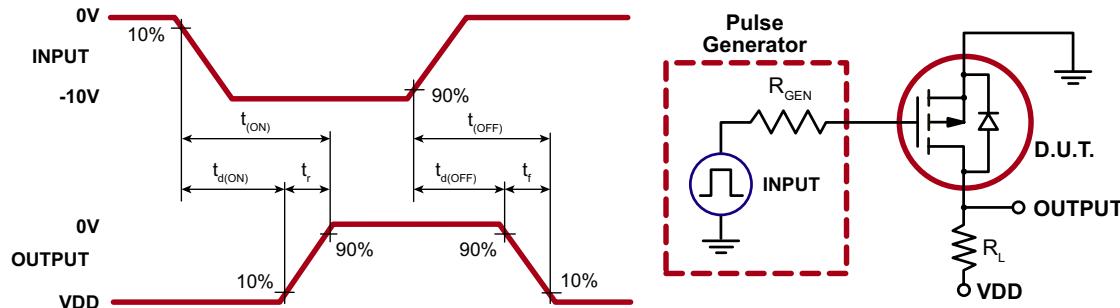
## Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Sym	Parameter	Min	Typ	Max	Units	Conditions
$BV_{DSS}$	Drain-to-source breakdown voltage	-16.5	-	-	V	$V_{GS} = 0\text{V}$ , $I_D = -1.0\text{mA}$
$V_{GS}$	Gate threshold voltage	-0.5	-0.7	-1.0	V	$V_{GS} = V_{DS}$ , $I_D = -1.0\text{mA}$
$\Delta V_{GS(\text{th})}$	Change in $V_{GS(\text{th})}$ with temperature	-	-	-4.0	mV/°C	$V_{GS} = V_{DS}$ , $I_D = -1.0\text{mA}$
$I_{GSS}$	Gate body leakage	-	-	-100	nA	$V_{GS} = \pm 10\text{V}$ , $V_{DS} = 0\text{V}$
$I_{DSS}$	Zero gate voltage drain current	-	-	-100	nA	$V_{DS} = -15\text{V}$ , $V_{GS} = 0\text{V}$
		-	-	-1.0	mA	$V_{DS} = 0.8$ Max Rating, $V_{GS} = 0\text{V}$ , $T_A = 125^\circ\text{C}$
$I_{D(\text{ON})}$	On-state drain current	-	-0.4	-	A	$V_{GS} = V_{DS} = -2.0\text{V}$
		-0.6	-1.0	-		$V_{GS} = V_{DS} = -3.0\text{V}$
		-1.25	-2.30	-		$V_{GS} = V_{DS} = -5.0\text{V}$
$R_{DS(\text{ON})}$	Static drain-to-source on-state resistance	-	2.0	4.0	$\Omega$	$V_{GS} = -2.0\text{V}$ , $I_D = -50\text{mA}$
		-	1.7	2.0		$V_{GS} = -3.0\text{V}$ , $I_D = -150\text{mA}$
		-	1.3	1.5		$V_{GS} = -5.0\text{V}$ , $I_D = -300\text{mA}$
$\Delta R_{DS(\text{ON})}$	Change in $R_{DS(\text{ON})}$ with temperature	-	-	0.75	%/°C	$V_{GS} = -5.0\text{V}$ , $I_D = -300\text{mA}$
$G_{FS}$	Forward transconductance	500	700	-	mmho	$V_{GS} = -15\text{V}$ , $I_D = -1.0\text{A}$
$C_{ISS}$	Input capacitance	-	120	250	pF	$V_{GS} = 0\text{V}$ ,
$C_{OSS}$	Common source output capacitance	-	100	125		$V_{DS} = -15\text{V}$ ,
$C_{RSS}$	Reverse transfer capacitance	-	40	60		$f = 1.0\text{MHz}$
$t_{d(\text{ON})}$	Turn-on delay time	-	-	20	ns	$V_{DD} = -15\text{V}$ , $I_D = -1.25\text{A}$ , $R_{\text{GEN}} = 25\Omega$
$t_r$	Rise time	-	-	20		
$t_{d(\text{OFF})}$	Turn-off delay time	-	-	30		
$t_f$	Fall time	-	-	30		
$V_{SD}$	Diode forward voltage drop	-	-1.2	-1.5	V	$V_{GS} = 0\text{V}$ , $I_{SD} = -500\text{mA}$

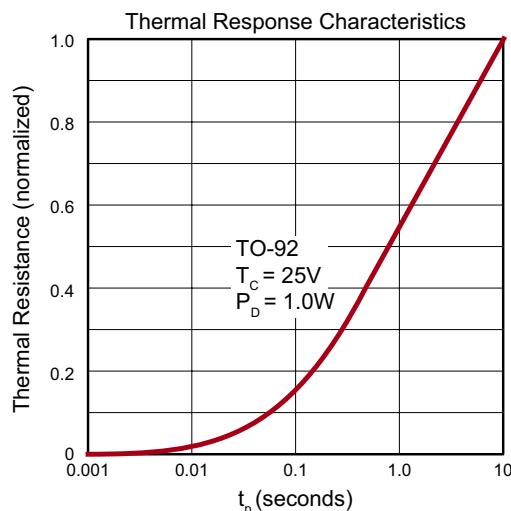
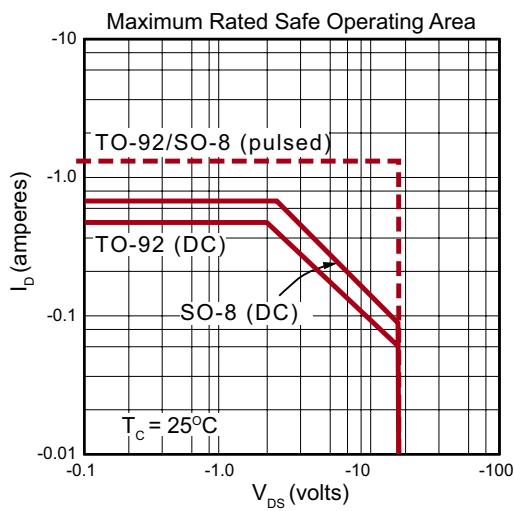
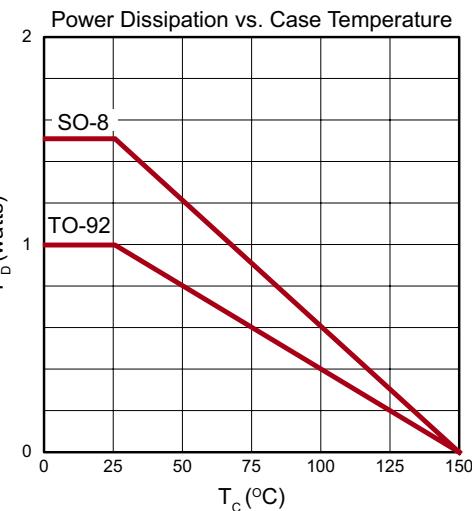
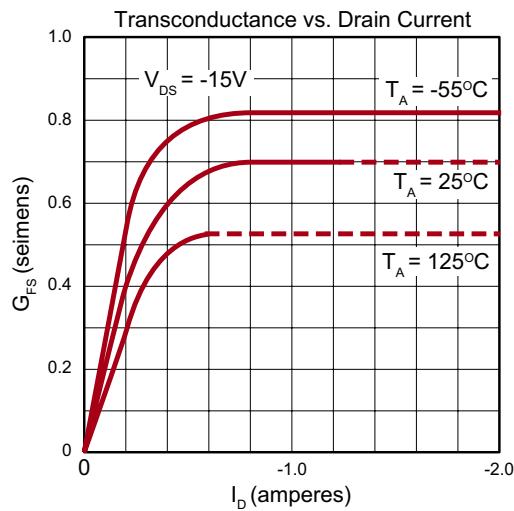
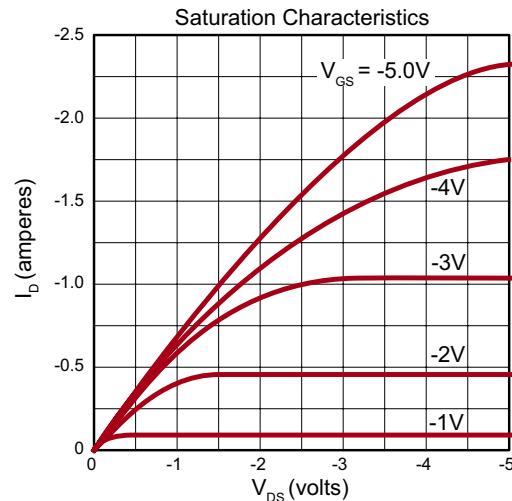
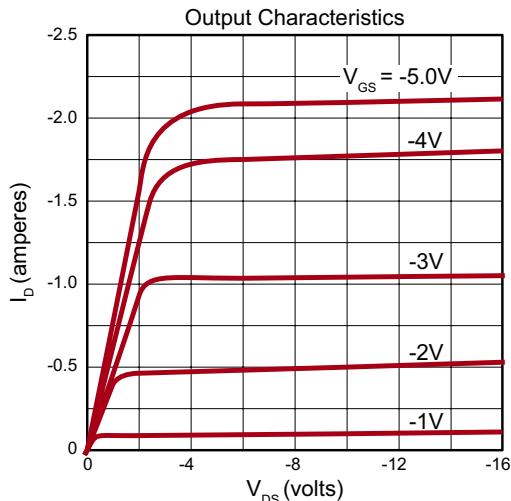
### Notes:

- All D.C. parameters 100% tested at  $25^\circ\text{C}$  unless otherwise stated. (Pulse test: 300μs pulse, 2% duty cycle.)
- All A.C. parameters sample tested.

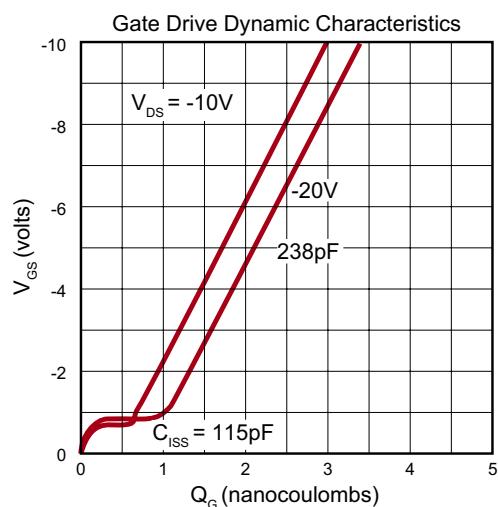
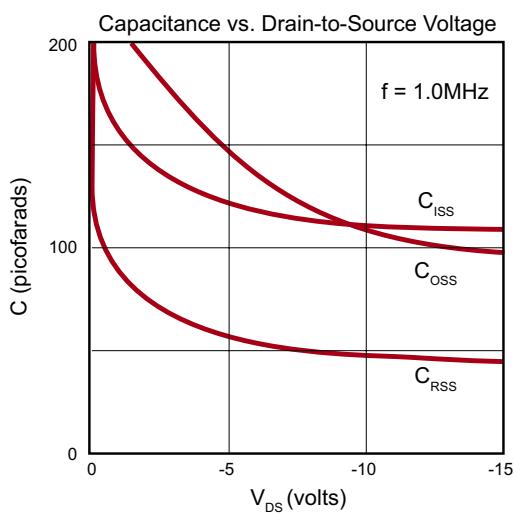
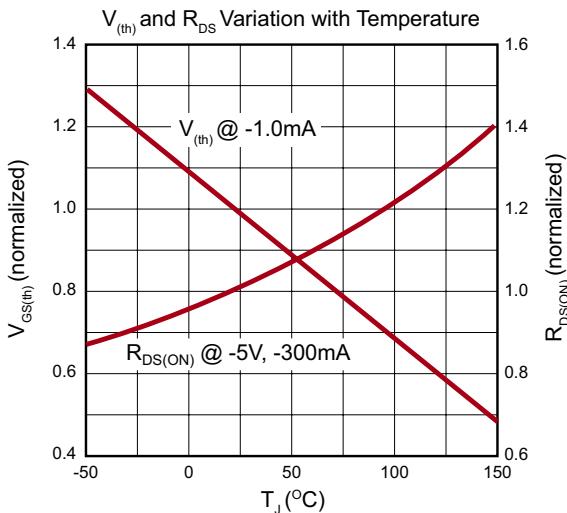
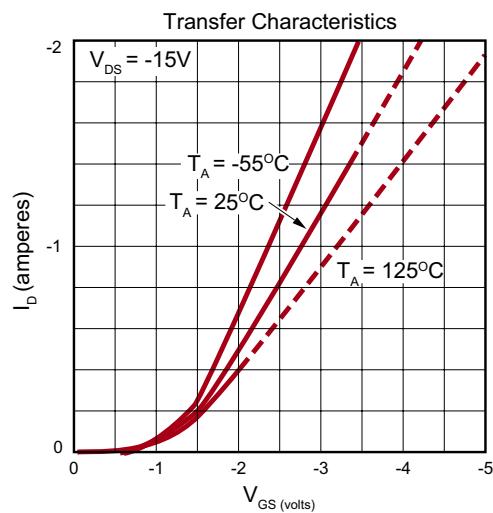
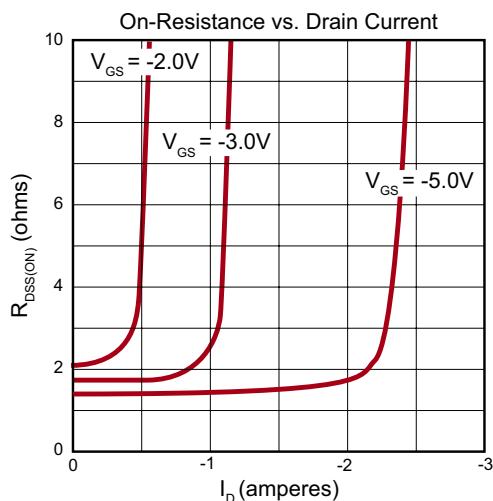
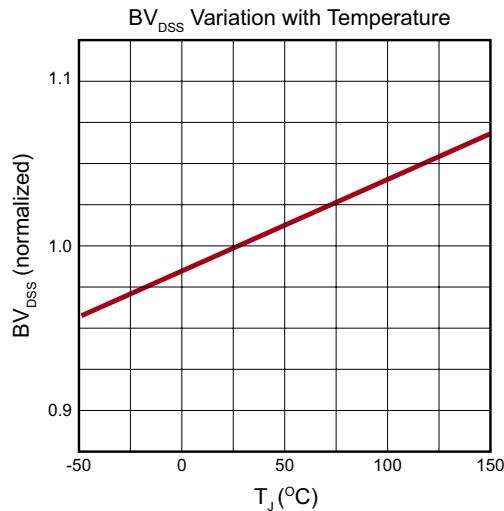
## Switching Waveforms and Test Circuit



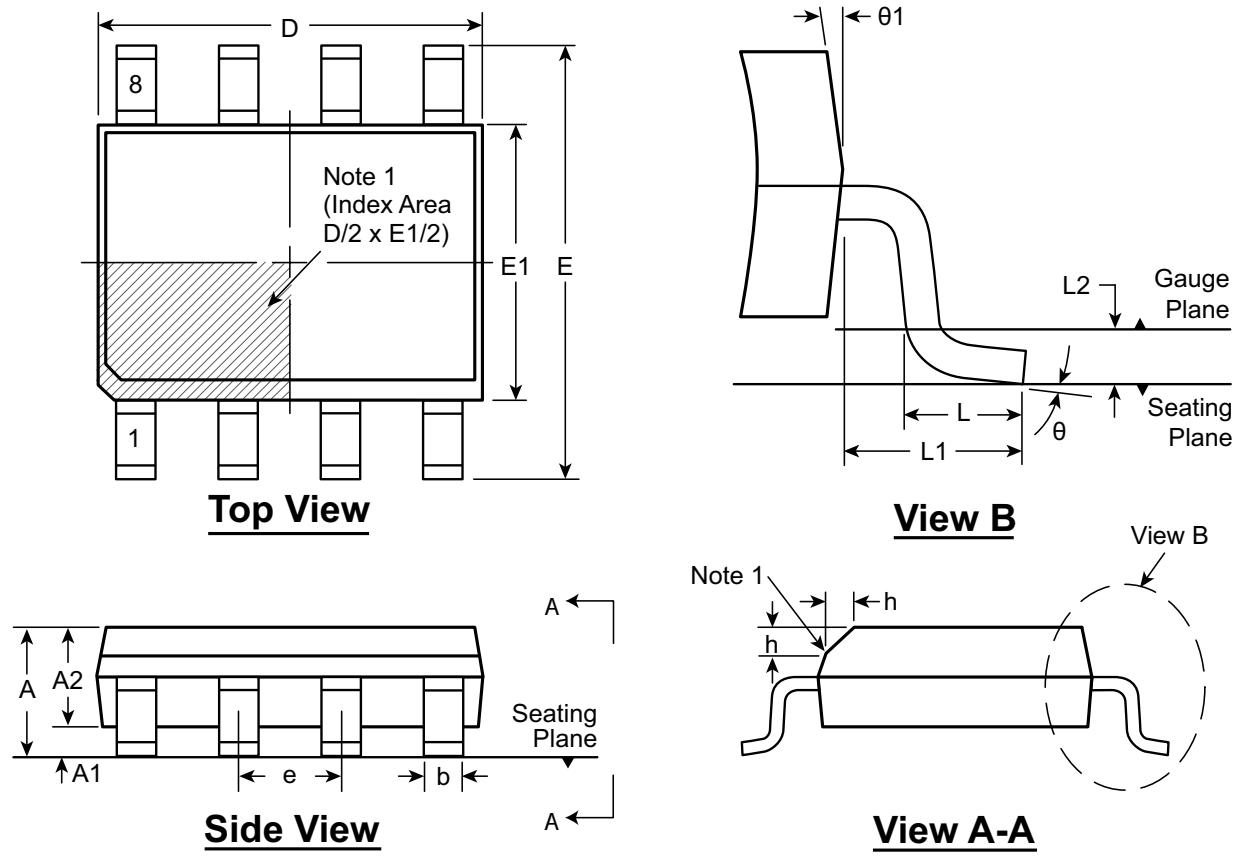
## Typical Performance Curves



## Typical Performance Curves (cont.)



# 8-Lead SOIC (Narrow Body) Package Outline (LG)



**Note:**

1. This chamfer feature is optional. A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.

Symbol	A	A1	A2	b	D	E	E1	e	h	L	L1	L2	θ	θ1
Dimension (mm)	MIN	1.35*	0.10	1.25	0.31	4.80*	5.80*	3.80*	0.25	0.40	1.04 REF	0.25 BSC	0°	5°
	NOM	-	-	-	-	4.90	6.00	3.90	-	-			-	-
	MAX	1.75	0.25	1.65*	0.51	5.00*	6.20*	4.00*	0.50	1.27			8°	15°

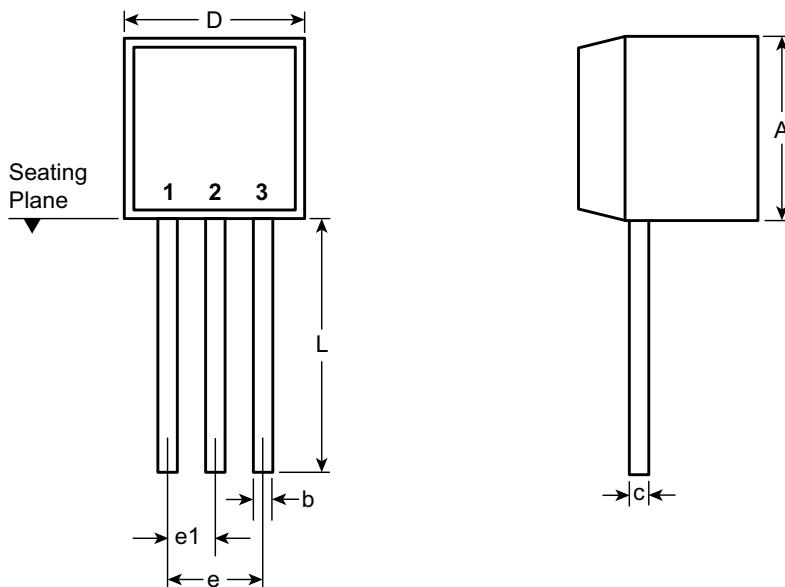
JEDEC Registration MS-012, Variation AA, Issue E, Sept. 2005.

\* This dimension is not specified in the JEDEC drawing.

Drawings are not to scale.

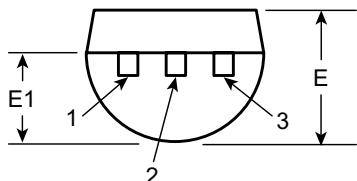
Supertex Doc. #: DSPD-8SOLGTG, Version I041309.

# 3-Lead TO-92 Package Outline (N3)



Front View

Side View



Bottom View

Symbol		A	b	c	D	E	E1	e	e1	L
Dimensions (inches)	MIN	.170	.014 <sup>†</sup>	.014 <sup>†</sup>	.175	.125	.080	.095	.045	.500
	NOM	-	-	-	-	-	-	-	-	-
	MAX	.210	.022 <sup>†</sup>	.022 <sup>†</sup>	.205	.165	.105	.105	.055	.610*

JEDEC Registration TO-92.

\* This dimension is not specified in the JEDEC drawing.

† This dimension differs from the JEDEC drawing.

Drawings not to scale.

Supertex Doc.#: DSFP-3TO92N3, Version E041009.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <http://www.supertex.com/packaging.html>.)

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